Low Voltage CMOS Hex Schmitt Inverter With 5 V-Tolerant Inputs

The MC74LCX14 is a high performance hex inverter with Schmitt–Trigger inputs operating from a 2.3 to 3.6 V supply. High impedance TTL compatible inputs significantly reduce current loading to input drivers, while TTL compatible outputs offer improved switching noise performance. A V_I specification of 5.5 V allows MC74LCX14 inputs to be safely driven from 5.0 V devices.

Pin configuration and function are the same as the MC74LCX04, but the inputs have hysteresis and, with its Schmitt trigger function, the LCX14 can be used as a line receiver which will receive slow input signals.

Features

- Designed for 2.3 V to 3.6 V V_{CC} Operation
- 5.0 V Tolerant Inputs Interface Capability with 5.0 V TTL Logic
- LVTTL Compatible
- LVCMOS Compatible
- 24 mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current (10 µA) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 500 mA
- Current Drive Capability is 24 mA at Source/Sink
- Pin and Function Compatible with Other Standard Logic Families
- ESD Performance: Human Body Model >2000 V Machine Model >100 V
- Chip Complexity: 41 Equivalent Gates
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



ON Semiconductor®

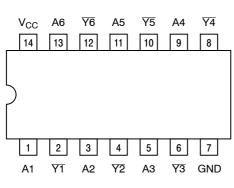
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			MARKING DIAGRAMS
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		= Assemb = Wafer L = Year = Work W = Pb-Free	/eek

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.







Pins	Function		
An	Data Inputs		
Yn	Outputs		

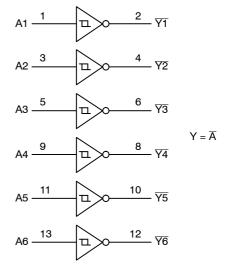


Figure 2. Logic Diagram

TRUTH TABLE

Inputs	Outputs
Α	Ÿ
L	н
Н	L

MAXIMUM RATINGS

Symbol	Parameter	Value	Condition	Units
V _{CC}	DC Supply Voltage	-0.5 to +7.0		V
VI	DC Input Voltage	$-0.5 \le V_{\rm l} \le +7.0$		V
Vo	DC Output Voltage	$-0.5 \leq V_{O} \leq V_{CC} + 0.5$	Output in HIGH or LOW State. (Note 1)	V
I _{IK}	DC Input Diode Current	-50	V _I < GND	mA
I _{OK}	DC Output Diode Current	-50	V _O < GND	mA
		+50	V _O > V _{CC}	mA
Ι _Ο	DC Output Source/Sink Current	±50		mA
I _{CC}	DC Supply Current Per Supply Pin	±100		mA
I _{GND}	DC Ground Current Per Ground Pin	±100		mA
T _{STG}	Storage Temperature Range	–65 to +150		°C
MSL	Moisture Sensitivity		Level 1	

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected. 1. I_O absolute maximum rating must be observed.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Тур	Max	Units
V _{CC}	Supply Voltage				V
	Operating	2.0	2.5 to 3.3	3.6	
	Data Retention Only	1.5		3.6	
VI	Input Voltage	0		5.5	V
Vo	Output Voltage (HIGH or LOW State)	0		V _{CC}	V
I _{OH}	HIGH Level Output Current				mA
	V _{CC} = 3.0 V–3.6 V			-24	
	V _{CC} = 2.7 V–3.0 V			-12	
	$V_{CC} = 2.3 \text{ V} - 2.7 \text{ V}$			-8	
I _{OL}	LOW Level Output Current				mA
	V _{CC} = 3.0 V–3.6 V			+24	
	V _{CC} = 2.7 V–3.0 V			+12	
	$V_{CC} = 2.3 \text{ V} - 2.7 \text{ V}$			+8	
TA	Operating Free-Air Temperature	-40		+85	°C

DC ELECTRICAL CHARACTERISTICS

			T _A = -40	to 85°C	
Symbol	Characteristic	Condition	Min	Max	Units
V_{T+}	Positive Input Threshold Voltage (Figure 3)	V _{CC} = 2.5 V V _{CC} = 3.0 V	0.9 1.2	1.7 2.2	V
V_{T-}	Negative Input Threshold Voltage (Figure 3)	V _{CC} = 2.5 V V _{CC} = 3.0 V	0.4 0.6	1.1 1.5	V
V _H	Input Hysteresis Voltage (Figure 3)	V _{CC} = 2.5 V V _{CC} = 3.0 V	0.3 0.4	1.0 1.2	V
V _{OH}	HIGH Level Output Voltage	$2.3 \text{ V} \leq \text{V}_{\text{CC}} \leq 3.6 \text{ V}; \text{ I}_{\text{OL}} = 100 \mu\text{A}$	V _{CC} – 0.2		V
	-	$V_{CC} = 2.3 \text{ V}; \text{ I}_{OH} = -8 \text{ mA}$	1.8		
		$V_{CC} = 2.7 \text{ V}; \text{ I}_{OH} = -12 \text{ mA}$	2.2		
		$V_{CC} = 3.0 \text{ V}; \text{ I}_{OH} = -18 \text{ mA}$	2.4		
		$V_{CC} = 3.0 \text{ V}; \text{ I}_{OH} = -24 \text{ mA}$	2.2		
V _{OL}	LOW Level Output Voltage	$2.3 \text{ V} \leq \text{V}_{\text{CC}} \leq 3.6 \text{ V}; \text{ I}_{\text{OL}} = 100 \ \mu\text{A}$		0.2	V
		$V_{CC} = 2.3 \text{ V}; I_{OL} = 8 \text{ mA}$		0.3	
		V _{CC} = 2.7 V; I _{OL} = 12 mA		0.4	
	-	V _{CC} = 3.0 V; I _{OL} = 16 mA		0.4	
		V _{CC} = 3.0 V; I _{OL} = 24 mA		0.55	
I _{OFF}	Power Off Leakage Current	V_{CC} = 0, V_{IN} = 5.5 V or V_{OUT} = 5.5 V		10	μA
I _{IN}	Input Leakage Current	V_{CC} = 3.6 V, V_{IN} = 5.5 V or GND		±5.0	μA
I _{CC}	Quiescent Supply Current	V_{CC} = 3.6 V, V_{IN} = 5.5 V or GND		10	μA
ΔI_{CC}	Increase in I _{CC} per Input	$2.3 \le V_{CC} \le 3.6 \text{ V}; \text{ V}_{IH} = V_{CC} - 0.6 \text{ V}$		500	μΑ

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 2.5 \text{ ns}$)

			Limits						
				$T_A = -40^{\circ}C$ to $+85^{\circ}C$					
			$V_{CC} = 3.3 \ V \pm 0.3 \ V \\ V_{CC} = 2.7 \ V \\ V_{CC} = 2.5 \ V \pm 0.2 \ V \\ \label{eq:VCC}$						
			C _L = 50 pF C _L = 50 pF C _L = 30 pF						
Symbol	Parameter	Waveform	Min	Max	Min	Max	Min	Max	Units
t _{PLH} t _{PHL}	Propagation Delay Input to Output	1	1.5 1.5	6.5 6.5	1.5 1.5	7.5 7.5	1.5 1.5	7.8 7.8	ns
t _{OSHL} t _{OSLH}	Output-to-Output Skew (Note 2)			1.0 1.0					ns

 Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}); parameter guaranteed by design.

DYNAMIC SWITCHING CHARACTERISTICS

			T _A = +25°C			
Symbol	Characteristic	Condition	Min	Тур	Max	Units
V _{OLP}	Dynamic LOW Peak Voltage (Note 3)	$ \begin{array}{l} V_{CC} = 3.3 \text{ V}, \ C_L = 50 \text{ pF}, \ V_{IH} = 3.3 \text{ V}, \ V_{IL} = 0 \text{ V} \\ V_{CC} = 2.5 \text{ V}, \ C_L = 30 \text{ pF}, \ V_{IH} = 2.5 \text{ V}, \ V_{IL} = 0 \text{ V} \end{array} $		0.8 0.6		V
V _{OLV}	Dynamic LOW Valley Voltage (Note 3)			-0.8 -0.6		V

3. Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Units
C _{IN}	Input Capacitance	V_{CC} = 3.3 V, V_{I} = 0 V or V_{CC}	7	pF
C _{OUT}	Output Capacitance	V_{CC} = 3.3 V, V_{I} = 0 V or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	10 MHz, V_{CC} = 3.3 V, V_{I} = 0 V or V_{CC}	25	pF

ORDERING INFORMATION

Device	Package	Shipping [†]
MC74LCX14DG	SOIC-14 (Pb-Free)	55 Units / Rail
MC74LCX14DR2G	SOIC-14 (Pb-Free)	2500 Tape & Reel
MC74LCX14DTG	TSSOP-14 (Pb-Free)	96 Units / Rail
MC74LCX14DTR2G	TSSOP-14 (Pb-Free)	2500 Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

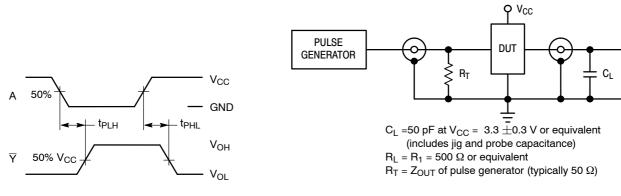
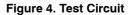


Figure 3. Switching Waveforms



 $\leq R_L$

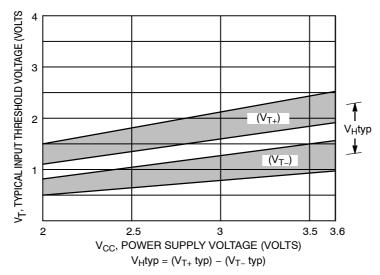
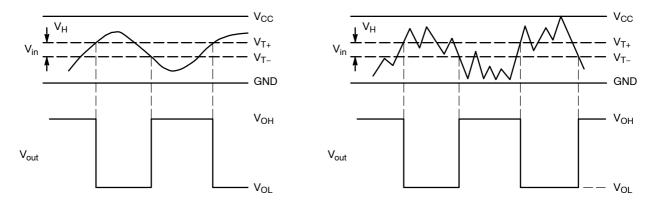
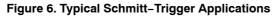


Figure 5. Typical Input Threshold, $V_{T\scriptscriptstyle +}, V_{T\scriptscriptstyle -}$ versus Power Supply Voltage

(a) A Schmitt-Trigger Squares Up Inputs With Slow Rise and Fall Times

(b) A Schmitt-Trigger Offers Maximum Noise Immunity





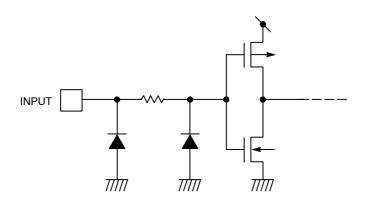


Figure 7. Input Equivalent Circuit

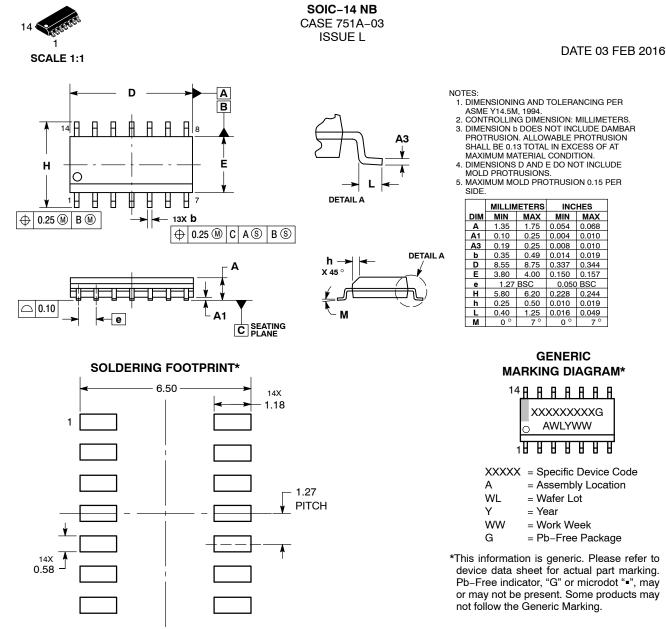
DUSEM

0.068

0.019

0.344

0.244



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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DATE 03 FEB 2016

STYLE 1: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. NO CONNECTION 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. NO CONNECTION 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 2: CANCELLED	STYLE 3: PIN 1. NO CONNECTION 2. ANODE 3. ANODE 4. NO CONNECTION 5. ANODE 6. NO CONNECTION 7. ANODE 8. ANODE 9. ANODE 10. NO CONNECTION 11. ANODE 12. ANODE 13. NO CONNECTION 14. COMMON CATHODE	STYLE 4: PIN 1. NO CONNECTION 2. CATHODE 3. CATHODE 4. NO CONNECTION 5. CATHODE 6. NO CONNECTION 7. CATHODE 8. CATHODE 9. CATHODE 10. NO CONNECTION 11. CATHODE 12. CATHODE 13. NO CONNECTION 14. COMMON ANODE
STYLE 5:	STYLE 6:	STYLE 7:	STYLE 8:
PIN 1. COMMON CATHODE	PIN 1. CATHODE	PIN 1. ANODE/CATHODE	PIN 1. COMMON CATHODE
2. ANODE/CATHODE	2. CATHODE	2. COMMON ANODE	2. ANODE/CATHODE
3. ANODE/CATHODE	3. CATHODE	3. COMMON CATHODE	3. ANODE/CATHODE
4. ANODE/CATHODE	4. CATHODE	4. ANODE/CATHODE	4. NO CONNECTION
5. ANODE/CATHODE	5. CATHODE	5. ANODE/CATHODE	5. ANODE/CATHODE
6. NO CONNECTION	6. CATHODE	6. ANODE/CATHODE	6. ANODE/CATHODE
7. COMMON ANODE	7. CATHODE	7. ANODE/CATHODE	7. COMMON ANODE
8. COMMON CATHODE	8. ANODE	8. ANODE/CATHODE	8. COMMON ANODE
9. ANODE/CATHODE	9. ANODE	10. ANODE/CATHODE	9. ANODE/CATHODE
10. ANODE/CATHODE	10. ANODE	11. COMMON CATHODE	10. ANODE/CATHODE
11. ANODE/CATHODE	11. ANODE	12. COMMON CATHODE	11. NO CONNECTION
12. ANODE/CATHODE	12. ANODE	13. ANODE/CATHODE	12. ANODE/CATHODE
13. NO CONNECTION	13. ANODE	14. ANODE/CATHODE	13. ANODE/CATHODE
14. COMMON ANODE	14. ANODE	14. ANODE/CATHODE	14. COMMON CATHODE

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